imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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Power MOSFETs

2SK3318

Silicon N-channel power MOSFET

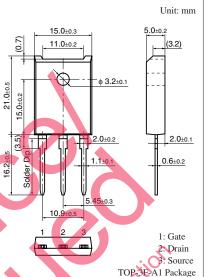
For switching

Features

- Avalanche energy capability guaranteed
- High-speed switching
- Low ON resistance R_{on}
- No secondary breakdown

Absolute Maximum Ratings $T_C = 25^{\circ}C$

Symbol	Rating	Unit	
V _{DSS}	600	V	
V _{GSS}	±30	V	
ID	±15	A	
I _{DP}	±60	A	
EAS	112.5	mJ	
P _D	100	W	
	3		
T _{ch}	150	°C	
T _{stg}	-55 to +150	°C	
	V_{DSS} V_{GSS} I_D I_{DP} EAS P_D T_{ch}	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $





Note) *: L = 1 mH, $I_L = 15 \text{ A}$, 1 pulse

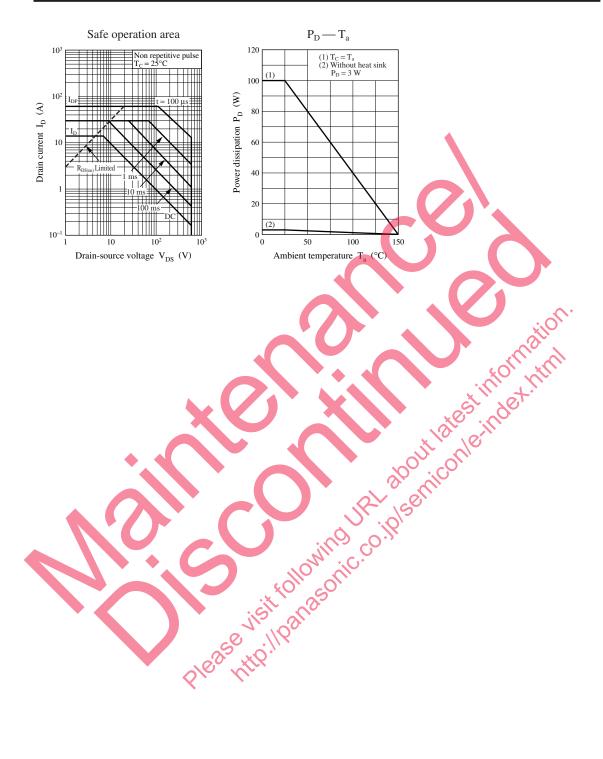
Electrical Characteristics $T_c = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Gate-drain surrender voltage	V _{DSS}	$I_{\rm D} = 1 \text{ mA}, V_{\rm GS} = 0$	600			V
Diode forward voltage	V _{DSF}	$I_{DR} = 15 \text{ A}, V_{GS} = 0$			-1.5	V
Gate threshold voltage	V _{th}	$V_{\rm DS} = 25 \text{ V}, I_{\rm D} = 1 \text{ mA}$	2		4	V
Drain-source cutoff current	I _{DSS}	$V_{\rm DS} = 480 \text{V}, V_{\rm GS} = 0$			10	μΑ
Gate-source cutoff currentt	I _{GSS}	$V_{GS} = \pm 30 \text{ V} (V_{DS} = 0$			±1	μΑ
Drain-source on resistance	R _{DS(on)}	$V_{GS} = 10$ V, $I_D = 7.5$ A		0.33	0.46	Ω
Forward transfer admittance	Y _{fs}	$V_{DS} = 25 \text{ V}, \text{ I}_{D} = 7.5 \text{ A}$	6	10		S
Short-circuit forward transfer capacitance (Common-source)	Ciss	$V_{BS} = 20 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$		3 500		pF
Short-circuit output capacitance (Common-source)	Coss			340		pF
Reverse transfer capacitance (Common-source)	C _{rss}			50		pF
Turn-on delay time	t _{d(on)}	V _{DD} = 150 V, I _D = 7.5 A		40		ns
Rise time	t _r	$R_L = 20 \Omega, V_{GS} = 10 V$		55		ns
Turn-off delay time	t _{d(off)}			310		ns
Fall time	t _f			70		ns
Channel-case heat resistance	R _{th(ch-c)}				1.25	°C/W
Channel-atmosphere heat resistance	R _{th(ch-a)}				41.7	°C/W

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2SK3318





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